Diode Semiconductor Device - Page 1 of 1

AeroBase Group

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# Inclosure Material:

Glass

# Overall Length:

Between 0.200 inches and 0.260 inches

# **Terminal Length:**

Between 0.900 inches and 1.250 inches

# **Overall Diameter:**

Between 0.160 inches and 0.230 inches

#### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

200.0 working peak reverse voltage, peak total value

# **Current Rating Per Characteristic:**

125.00 amperes forward current, average pascal

# **Power Rating Per Characteristic:**

18.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead

# **Specification Data:**

81349-mil-s-19500/432 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

# Fiig:

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